imall

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ineup

2SJ0164 (2SJ164)

Silicon P-channel junction FET

For switching circuits Complementary to 2SK1104

Features

- Low ON resistance
- Low-noise characteristics

Absolute Maximum Ratings $T_a = 25^{\circ}C$

| Abaaluta Maximum Dat | ingo T | 500 | | • Pin Name |
|-----------------------------------|------------------|-------------|----------|------------------------|
| Absolute Maximum Rat Parameter | Symbol | Rating | Unit | - 1: Source 2: Gate |
| | , | 0 | Unit | - 3: Dram |
| Gate-drain surrender voltage | V _{GDS} | 65 | V | - (1 × 10 |
| Drain current | ID | -20 | mA | |
| Gate current | I _G | -10 | mA | |
| Power dissipation | PD | 300 | mW | A A AN |
| Channel temperature | T _{ch} | 150 | °°°, | N . O CO. |
| Storage temperature | T _{stg} | -55 to +250 | C,C | AN NOS |
| | | S | C | |

| Electrical Characteristics T. 225°C ±3°C | | | | | | | | | | |
|---|--------|-----|-------|------|--|--|--|--|--|--|
| Parameter Symbol Sounditions | Min | Тур | Max | Unit | | | | | | |
| | IVIIII | тур | IVIAX | Unit | | | | | | |
| Gate-drain surrender voltage $V_{GDS} \times V_G = 10$ kA, $V_{DS} = 0$ | 65 | | | V | | | | | | |
| Drain-source current $V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0$ | - 0.6 | | -6.0 | mA | | | | | | |
| Gate-source cutoff curtent V_{GSS} , $V_{GS} = 30 \text{ V}$, $V_{DS} = 0$ | | | 10 | nA | | | | | | |
| Gate-source cutoff voltage V_{GS} $V_{DS} = -10 \text{ V}, \text{ I}_D = -10 \mu\text{A}$ | | 1.5 | 3.5 | V | | | | | | |
| Mutual conductance $V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}, f = 1 \text{ k}$ | Hz 1.8 | 2.5 | | mS | | | | | | |
| Short-circuit forward mansfer capacitance C_{iss} $V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | | 10 | | pF | | | | | | |
| (Common source) | | | | | | | | | | |
| Reverse transfer capacitance Crss | | 3 | | pF | | | | | | |
| (Common source) | | | | | | | | | | |
| Drain-source ON resistance $R_{DS(on)}$ $V_{DS} = -10 \text{ mV}, V_{GS} = 0$ | | 300 | | Ω | | | | | | |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

- 2. Observe precautions for handling. Electrostatic sensitive devices.
- 3. *: Rank classification

| Rank | Р | Q | R | |
|-----------------------|---------------|--------------|--------------|--|
| I _{DSS} (mA) | - 0.6 to -1.5 | -1.0 to -3.0 | -2.5 to -6.0 | |

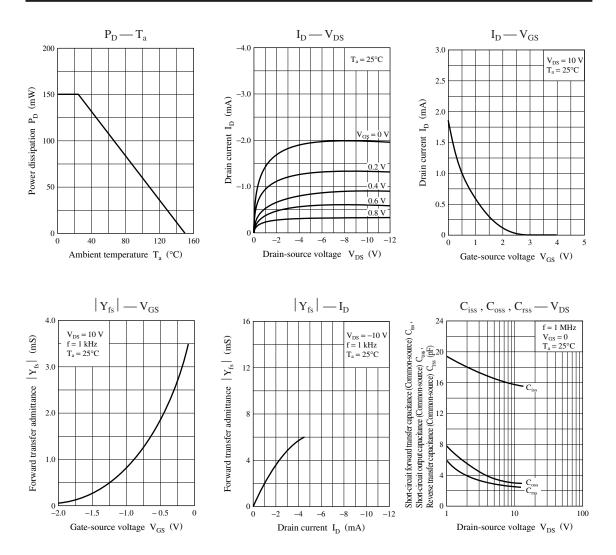
Note) The part number in the parenthesis shows conventional part number.

Package

Pin Name

 Code NS-A1

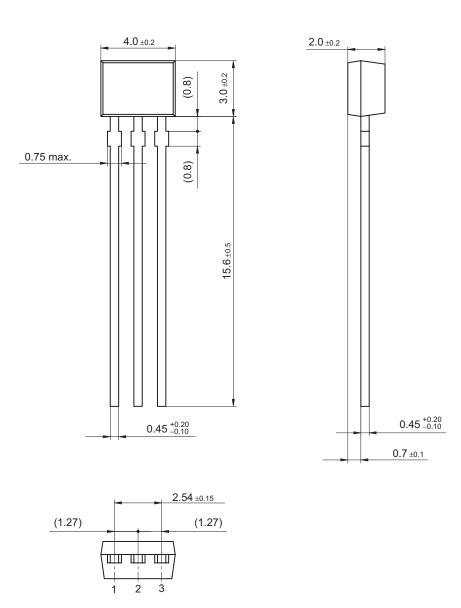
2SJ0164



Panasonic

NS-A1

Unit: mm



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